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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision * (September 2000) to Revision A (August 2023)	Page
• Updated the numbering format for tables, figures, and cross-references throughout the document.....	1
• Added the <i>Package Information</i> table, and the <i>Pin Configuration and Functions</i> , <i>Specifications</i> , <i>ESD Ratings</i> , <i>Recommended Operating Conditions</i> , <i>Thermal Information</i> , <i>Application and Implementation</i> , <i>Device and Documentation Support</i> , and <i>Mechanical, Packaging, and Orderable Information</i> sections.....	1
• Deleted PDIP package from data sheet.....	1
• Added single supply specification to Absolute Maximum Ratings.....	4
• Added note that output short-circuit (to ground) means short-circuit to $V_S/2$ in Absolute Maximum Ratings....	4
• Added "TA = –40°C to +85°C" test condition to Offset voltage vs temperature specification in the Electrical Characteristics and renamed to Offset voltage drift.....	5
• Added test conditions "VREF = 0 V, VCM = $V_S / 2$ and G = 10 below the title.....	5
• Deleted common-mode voltage typical values in the Electrical Characteristics and combined to one line.....	5
• Added "TA = –40°C to +85°C" test condition to Bias current vs temperature specification in the Electrical Characteristics and renamed to Input bias current drift for clarity.....	5
• Added "TA = –40°C to +85°C" test condition to Offset current vs temperature specification in Electrical Characteristics and renamed to Input offset current drift for clarity.....	5
• Added "TA = –40°C to +85°C" test condition for Gain error vs temperature in the Electrical Characteristics and renamed to Gain drift for clarity.....	5
• Changed parameter names from "Voltage - Positive" and "Voltage - Negative" to "Output voltage" in the Electrical Characteristics.....	5
• Added "Continuous to $V_S / 2$ " test condition short-circuit current specification in the Electrical Characteristics for clarity.....	5
• Changed short-circuit current typical value from +6/-15 mA ± 20 mA.....	5
• Changed bandwidth typical value from 1 MHz to 610 kHz in the Electrical Characteristics.....	5
• Changed slew rate typical value from 4 V/ μ s to 2 V/ μ s in the Electrical Characteristics.....	5
• Deleted redundant voltage range, operating temperature range, and specification temperature range specifications from Electrical Characteristics.....	5
• Changed Figure 6-2, <i>Common-Mode Rejection vs Frequency</i>	7
• Changed Figure 6-8, <i>Quiescent Current and Slew Rate vs Temperature</i>	7
• Changed <i>Output Voltage Swing vs Output Current</i> single plot to Figure 6-12, <i>Positive Output Voltage Swing vs Output Current</i> and Figure 6-12, <i>Negative Output Voltage Swing vs Output Current</i>	7
• Changed Figure 6-18, <i>Small-Signal Step Response</i>	7
• Changed Figure 6-19, <i>Large-Signal Step Response</i>	7
• Changed Figure 6-20, <i>0.1-Hz to 10-Hz Input-Referred Voltage Noise</i>	7
• Changed G from 1 to 10 V/V at the end of the <i>Application Information</i> section.....	11
• Deleted reference to <i>Input Bias Current vs Common-Mode Input Voltage</i> plot.....	13

5 Pin Configuration and Functions

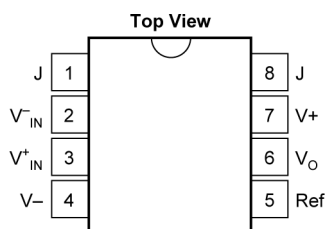


Figure 5-1. D Package, 8-Pin SOIC (Top View)

Table 5-1. Pin Functions

PIN		TYPE	DESCRIPTION
NAME	NO.		
J	1, 8	Input	Gain selection. G = 10 V/V if not shorted G = 100 V/V if shorted A resistance of 0.5 Ω decreases gain by 0.1%.
Ref	5	Input	Reference input. This pin must be driven by low impedance
V–	4	—	Negative supply
V+	7	—	Positive supply
V [–] _{IN}	2	Input	Negative (inverting) input
V ⁺ _{IN}	3	Input	Positive (noninverting) input
V _O	6	Output	Output

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _S	Supply voltage	Dual supply, V _S = (V+) – (V–)		±18	V
		Single supply, V _S = (V+) – 0 V		36	
	Input voltage			±40	V
	Output short-circuit (to ground) ⁽²⁾		Continuous		
T _A	Operating temperature		–40	125	°C
T _{stg}	Storage temperature		–40	125	°C
T _J	Junction temperature			150	°C
	Lead temperature (soldering, 10 s)			300	°C

- (1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) Short-circuit to V_S / 2.

6.2 ESD Ratings

			VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V
		Charged-device model (CDM), per ANSI/ESDA/JEDEC JS-002 ⁽²⁾	±250	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	TYP	MAX	UNIT
V _S	Supply voltage	Single-supply	4.5	30	36	V
		Dual-supply	±2.25	±15	±18	
T _A	Specified temperature		–40		85	°C

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		INA141	UNIT
		D (SOIC)	
		8 PINS	
θ _{JA}	Junction-to-ambient thermal resistance	150	°C/W
R _{θJA}	Junction-to-ambient thermal resistance	110	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	57	°C/W
R _{θJB}	Junction-to-board thermal resistance	54	°C/W
ψ _{JT}	Junction-to-top characterization parameter	11	°C/W
ψ _{JB}	Junction-to-board characterization parameter	53	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.5 Electrical Characteristics

at $T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{ V}$, $R_L = 10\text{ k}\Omega$, $V_{\text{REF}} = 0\text{ V}$, $V_{\text{CM}} = V_S / 2$, and $G = 10\text{ V/V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
INPUT								
V _{OS}	Offset voltage (RTI)	INA141P, INA141U	G = 10 V/V			±50	±100	μV
			G = 100 V/V			±20	±50	
		INA141PA, INA141UA	G = 10 V/V			±50	±250	
			G = 100 V/V			±20	±125	
	Offset voltage drift (RTI)	T _A = −40°C to +85°C	INA141P, INA141U	G = 10 V/V		±0.5	±2	μV/°C
				G = 100 V/V		±0.2	±0.5	
			INA141PA, INA141UA	G = 10 V/V		±0.5	±2.5	
				G = 100 V/V		±0.2	±1.5	
PSRR	Power-supply rejection ratio (RTI)	V _S = ±2.25 V to ±18 V	INA141P, INA141U	G = 10 V/V		±2	±10	μV/V
				G = 100 V/V		±0.4	±1	
			INA141PA, INA141UA	G = 10 V/V		±2	±20	
				G = 100 V/V		±0.4	±3	
	Long-term stability	G = 10 V/V				0.5		μV/mo
		G = 100 V/V				0.2		μV/mo
	Input impedance	Differential				100 2		GΩ pF
		Common-mode				100 9		
V _{CM}	Common-mode voltage ⁽¹⁾	V _O = 0 V			(V−) +2		(V+) − 2	V
CMRR	Common-mode rejection	V _{CM} = ±13 V, ΔR _S = 1 kΩ	INA141P, INA141U	G = 10 V/V	100	106		dB
				G = 100 V/V	117	125		
			INA141PA, INA141UA	G = 10 V/V	93	100		
				G = 100 V/V	110	120		
INPUT BIAS CURRENT								
I _B	Input bias current	INA141P, INA141U				±2	±5	nA
		INA141PA, INA141UA				±2	±10	
	Input bias current drift	T _A = −40°C to +85°C				±30		pA/°C
I _{OS}	Input offset current	INA141P, INA141U				±1	±5	nA
		INA141PA, INA141UA				±1	±10	nA
	Input offset current drift	T _A = −40°C to +85°C				±30		pA/°C
NOISE								
e _N	Voltage noise (RTI)	R _S = 0 Ω	G = 10 V/V	f = 10 Hz		22		nV/√Hz
				f = 100 Hz		13		
				f = 1 kHz		12		
				f _B = 0.1 Hz to 10 Hz		0.6		
			G = 100 V/V	f = 10 Hz		10		nV/√Hz
				f = 100 Hz		8		
				f = 1 kHz		8		
				f _B = 0.1 Hz to 10 Hz		0.2		
I _n	Current noise	f = 10 Hz				0.9		pA/√Hz
		f = 1 kHz				0.3		
		f _B = 0.1 Hz to 10 Hz				30		

6.5 Electrical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{ V}$, $R_L = 10\text{ k}\Omega$, $V_{\text{REF}} = 0\text{ V}$, $V_{\text{CM}} = V_S / 2$, and $G = 10\text{ V/V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
GAIN								
G	Gain				10	100		V/V
GE	Gain error	V _O = ±13.6 V	INA141P, INA141U	G = 10 V/V	±0.01	±0.05	%	
				G = 100 V/V	±0.03	±0.075		
			INA141PA, INA141UA	G = 10 V/V	±0.01	±0.15		
				G = 100 V/V	±0.03	±0.15		
	Gain drift ⁽⁶⁾	G = 10 V/V or 100 V/V, T _A = −40°C to +85°C			±2	±10		ppm/°C
	Gain nonlinearity	INA141P, INA141U	G = 10 V/V		±0.0003	±0.001	% of FSR	
			G = 100 V/V		±0.0005	±0.002		
		INA141PA, INA141UA	G = 10 V/V		±0.0003	±0.002		
			G = 100 V/V		±0.0005	±0.004		
OUTPUT								
	Output voltage				(V−) + 1.4	(V±) ∓ 0.9	(V+) − 1.4	V
C _L	Load capacitance	Stable operation			1000			pF
I _{SC}	Short-circuit current	Continuous to V _S / 2			±20			mA
FREQUENCY RESPONSE								
BW	Bandwidth, −3 dB	G = 10 V/V			610			kHz
		G = 100 V/V			200			kHz
SR	Slew rate	G = 10 V/V, V _O = ±10 V			2			V/μs
t _S	Settling time	To 0.01%, V _O = ±5 V	G = 10 V/V		7		μs	
			G = 100 V/V		9			
	Overload recovery	50% input overload			4			μs
POWER SUPPLY								
I _Q	Quiescent current	V _{IN} = 0 V			±750		±800	μA

(1) Input common-mode voltage varies with output voltage; see *Typical Characteristics*.

(2) Specified by wafer test.

6.6 Typical Characteristics

at $T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{ V}$, $V_{\text{REF}} = 0\text{ V}$, $G = 10\text{ V/V}$, $V_{\text{CM}} = V_S / 2$, and $R_L = 10\text{ k}\Omega$ (unless otherwise noted)

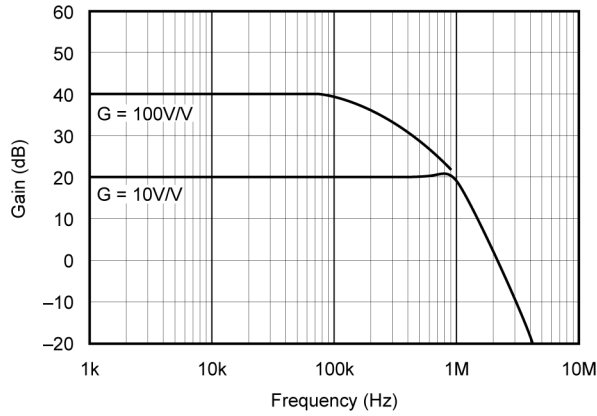


Figure 6-1. Gain vs Frequency

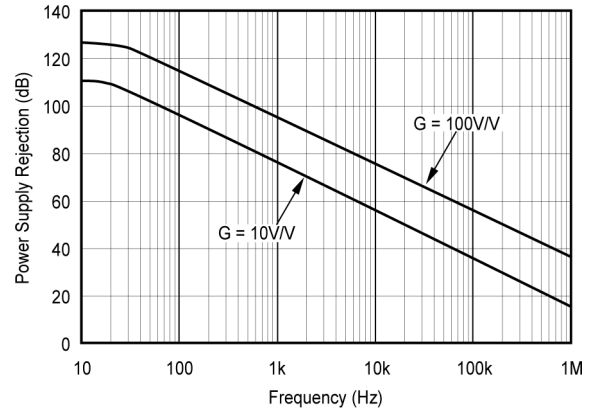


Figure 6-2. Common-Mode Rejection vs Frequency

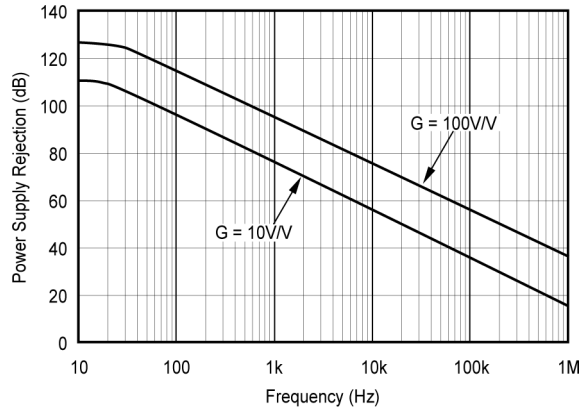


Figure 6-3. Positive Power Supply Rejection vs Frequency

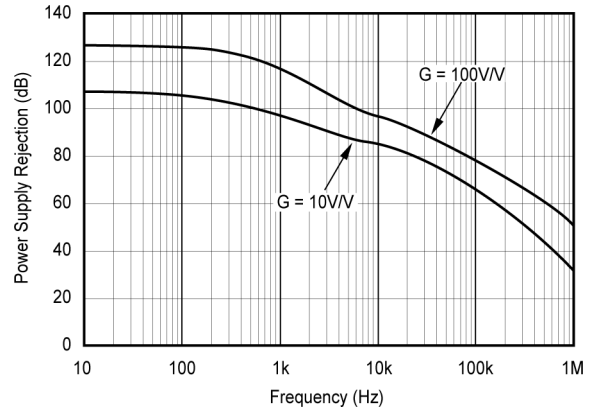


Figure 6-4. Negative Power Supply Rejection vs Frequency

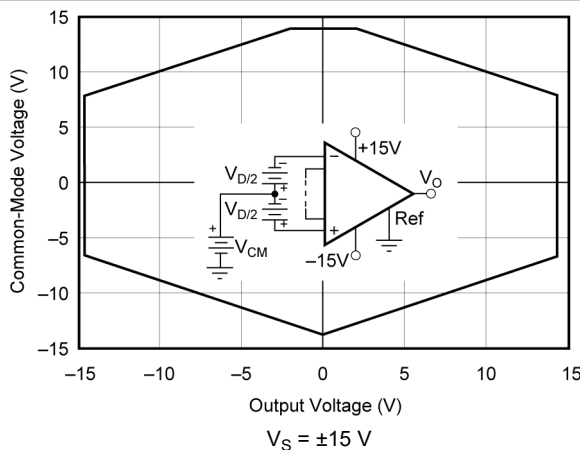


Figure 6-5. Input Common-Mode Range vs Output Voltage

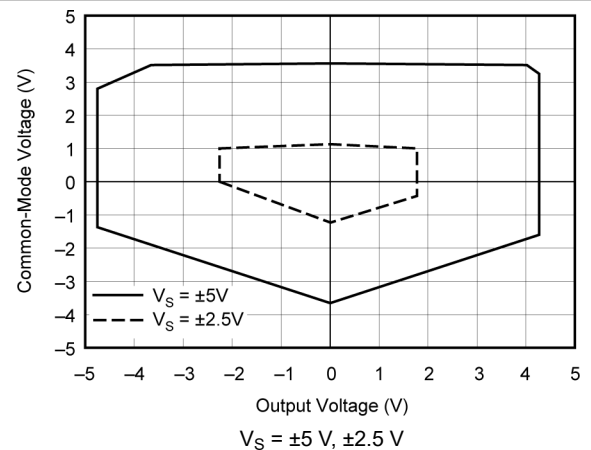


Figure 6-6. Input Common-Mode Range vs Output Voltage

6.6 Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{ V}$, $V_{\text{REF}} = 0\text{ V}$, $G = 10\text{ V/V}$, $V_{\text{CM}} = V_S / 2$, and $R_L = 10\text{ k}\Omega$ (unless otherwise noted)

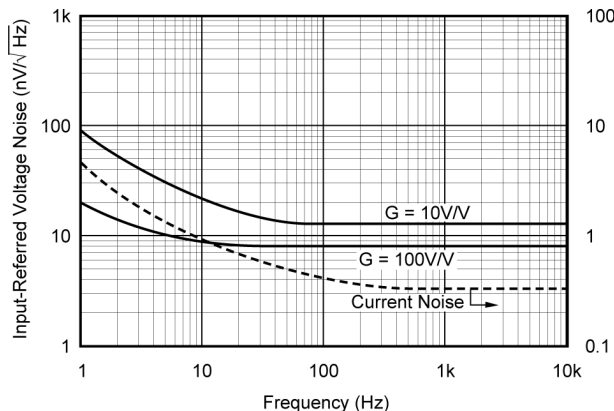


Figure 6-7. Input-Referred Noise vs Frequency

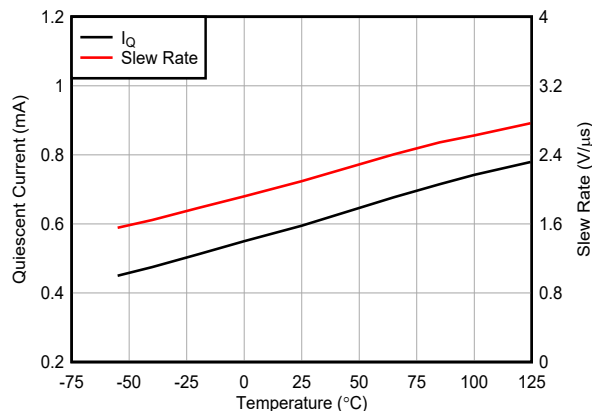


Figure 6-8. Quiescent Current and Slew Rate vs Temperature

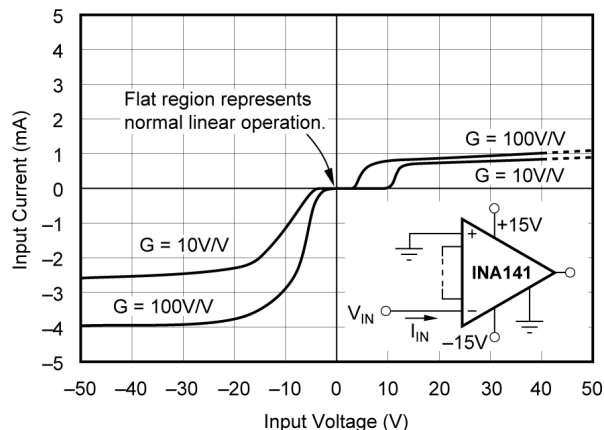


Figure 6-9. Input Overvoltage V/I Characteristics

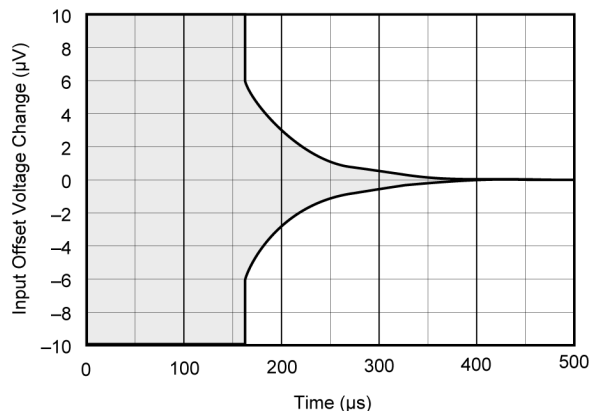


Figure 6-10. Input Offset Voltage Warmup

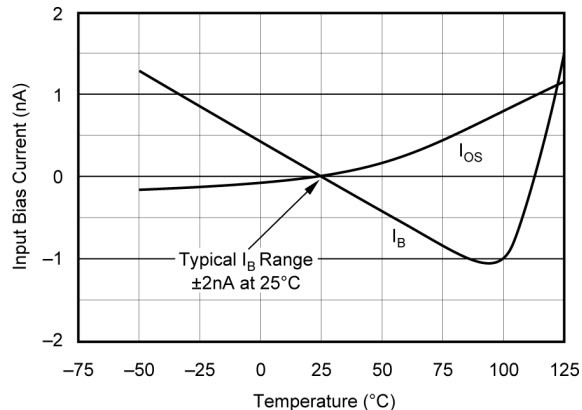


Figure 6-11. Input Bias Current vs Temperature

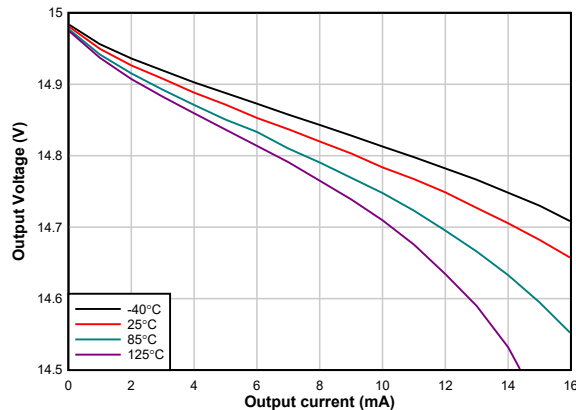


Figure 6-12. Positive Output Voltage Swing vs Output Current

6.6 Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{ V}$, $V_{\text{REF}} = 0\text{ V}$, $G = 10\text{ V/V}$, $V_{\text{CM}} = V_S / 2$, and $R_L = 10\text{ k}\Omega$ (unless otherwise noted)

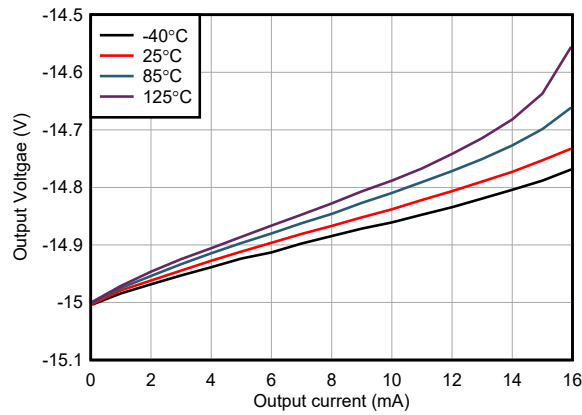


Figure 6-13. Negative Output Voltage Swing vs Output Current

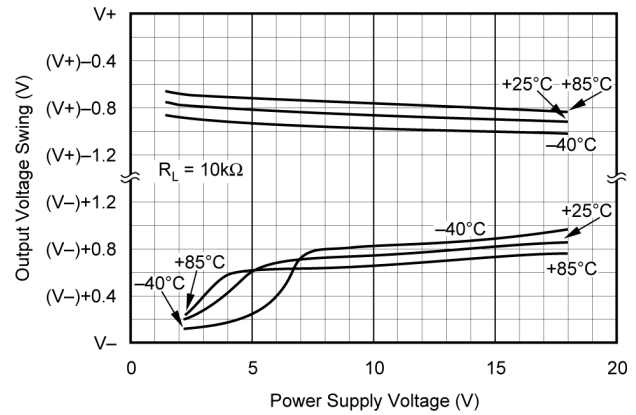


Figure 6-14. Output Voltage Swing vs Power Supply Voltage

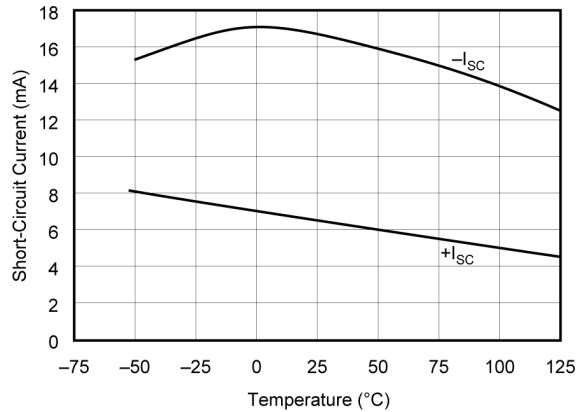


Figure 6-15. Short-circuit Output Current vs Temperature

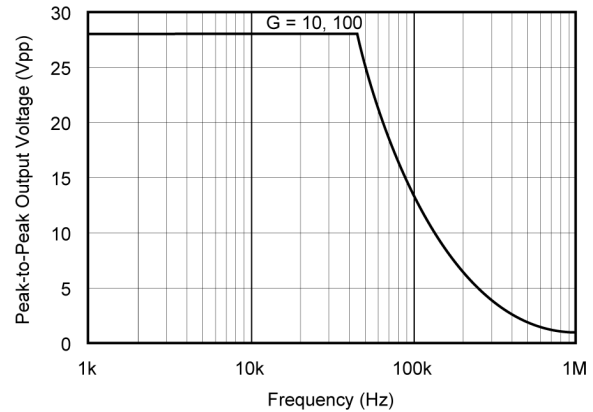


Figure 6-16. Maximum Output Voltage vs Frequency

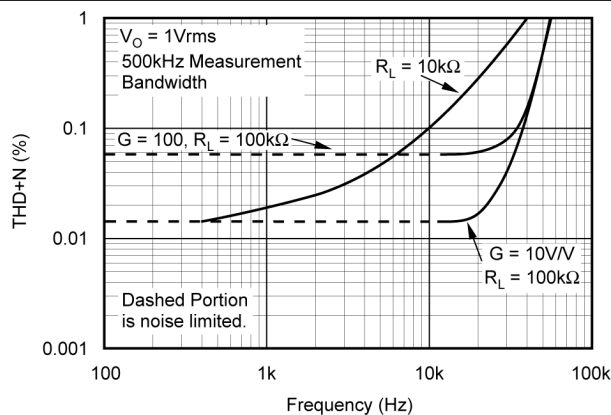


Figure 6-17. Total Harmonic Distortion + Noise vs Frequency

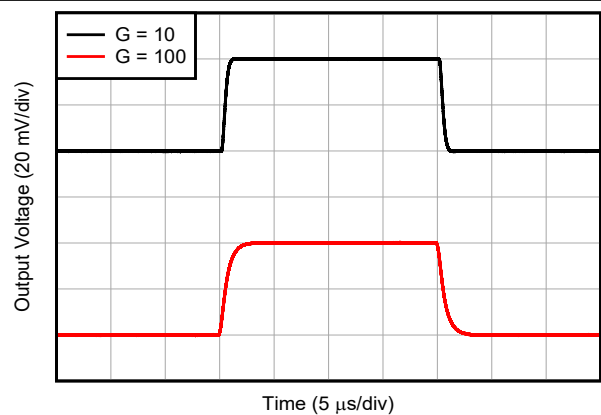


Figure 6-18. Small-Signal Step Response

6.6 Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{ V}$, $V_{\text{REF}} = 0\text{ V}$, $G = 10\text{ V/V}$, $V_{\text{CM}} = V_S / 2$, and $R_L = 10\text{ k}\Omega$ (unless otherwise noted)

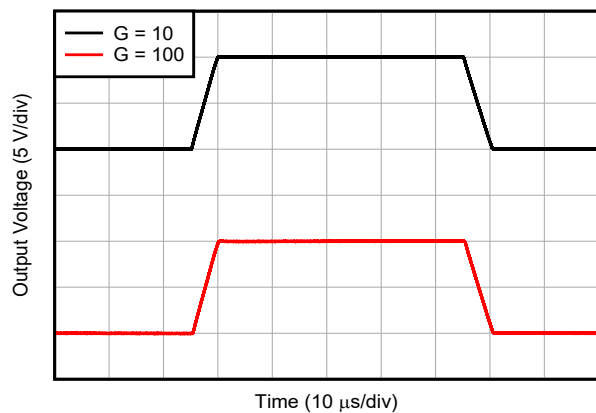


Figure 6-19. Large-Signal Step Response

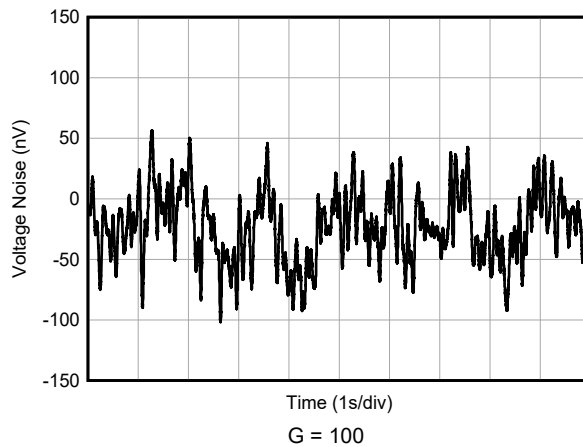


Figure 6-20. 0.1-Hz to 10-Hz Input-Referred Voltage Noise

7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Application Information

Figure 7-1 shows the basic connections required for operation of the INA141. Applications with noisy or high impedance power supplies can require decoupling capacitors close to the device pins as shown.

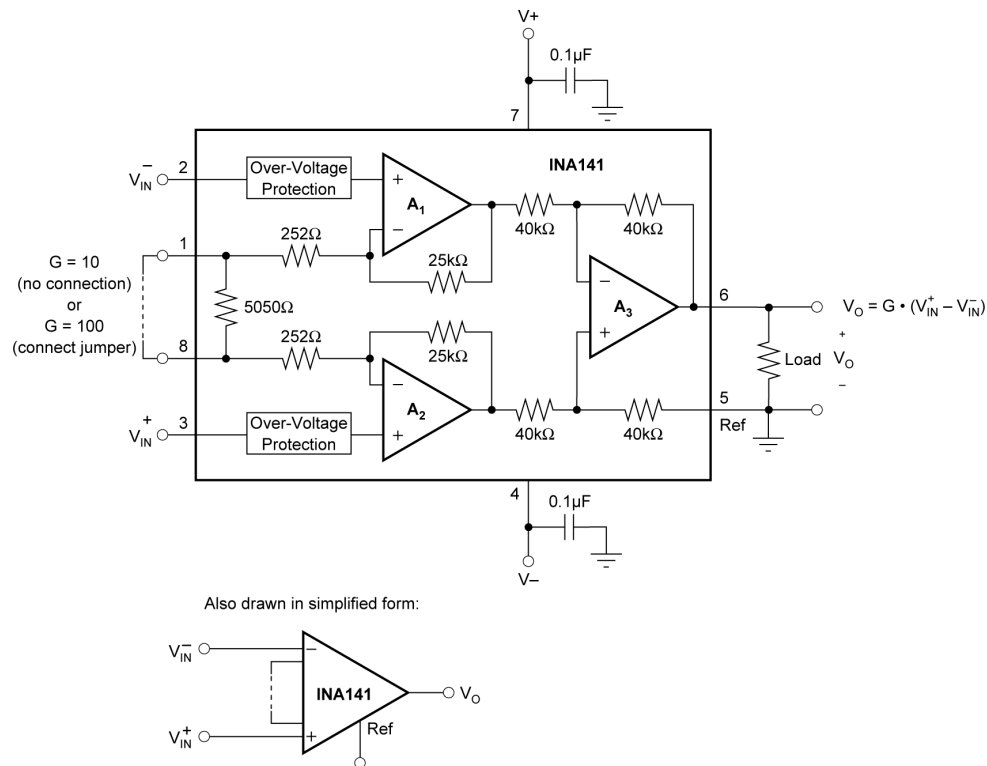


Figure 7-1. Basic Connections.

The output is referred to the output reference (Ref) pin, which is normally grounded. This connection must be low-impedance to maintain good common-mode rejection. A resistance of 8 Ω in series with the Ref pin causes a typical device to degrade to approximately 80 dB CMR ($G = 10$ V/V).

7.1.1 Setting the Gain

Gain is selected with a jumper connection (see Figure 7-1). With no jumper installed, $G = 10$ V/V. With a jumper installed, $G = 100$ V/V. To preserve good gain accuracy, this jumper must have low series resistance. A resistance of 0.5 Ω in series with the jumper decreases the gain by 0.1%.

Internal resistor ratios are laser trimmed to provide excellent gain accuracy. Actual resistor values can vary by approximately $\pm 25\%$ from the nominal values shown.

Gains between 10 V/V and 100 V/V are achieved by connecting an external resistor to the jumper pins. However, this configuration is not recommended because the $\pm 25\%$ variation of internal resistor values makes the required external resistor value uncertain. A companion model, the INA128, features accurately trimmed internal resistors so that gains from 1 V/V to 10,000 V/V can be set with an external resistor.

7.1.2 Dynamic Performance

Typical performance curve *Gain vs Frequency* (Figure 6-1) shows that, despite the low quiescent current, the INA141 achieves wide bandwidth, even at $G = 100$ V/V. This wide bandwidth is a result of the current-feedback topology of the INA141. Settling time also remains excellent at $G = 100$ V/V.

7.1.3 Noise Performance

The INA141 provides very low noise in most applications. Low-frequency noise is approximately $0.2 \mu\text{V}_{\text{PP}}$ measured from 0.1 Hz to 10 Hz ($G = 100$ V/V). The INA141 provides dramatically improved noise when compared to state-of-the-art, chopper-stabilized amplifiers.

7.1.4 Offset Trimming

The INA141 is laser trimmed for low offset voltage and offset voltage drift. Most applications require no external offset adjustment. Figure 7-2 shows an optional circuit for trimming the output offset voltage. The voltage applied to Ref pin is summed with the output. The op-amp buffer provides low impedance at the Ref pin to preserve good common-mode rejection.

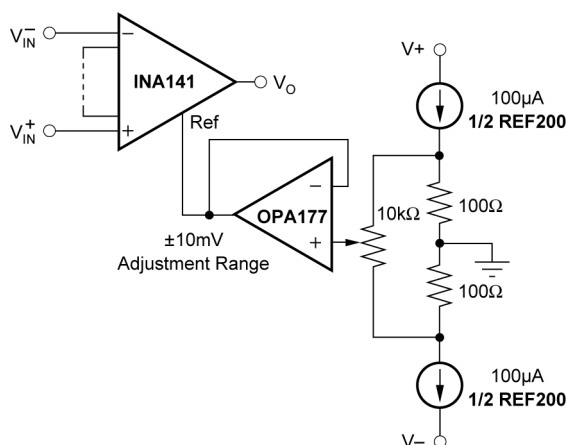


Figure 7-2. Optional Trimming of Output Offset Voltage.

7.1.5 Input Bias Current Return Path

The input impedance of the INA141 is extremely high—approximately $10^{10} \Omega$. However, a path must be provided for the input bias current of both inputs. This input bias current is approximately ± 2 nA. High input impedance means that this input bias current changes very little with varying input voltage.

Input circuitry must provide a path for this input bias current for proper operation. Figure 7-3 shows various provisions for an input bias current path. Without a bias current path, the inputs float to a potential that exceeds the common-mode range of the INA141 and the input amplifiers saturate.

If the differential source resistance is low, the bias current return path can be connected to one input (see the thermocouple example in Figure 7-3). With higher source impedance, using two equal resistors provides a balanced input with possible advantages of lower input offset voltage due to bias current and better high-frequency common-mode rejection.

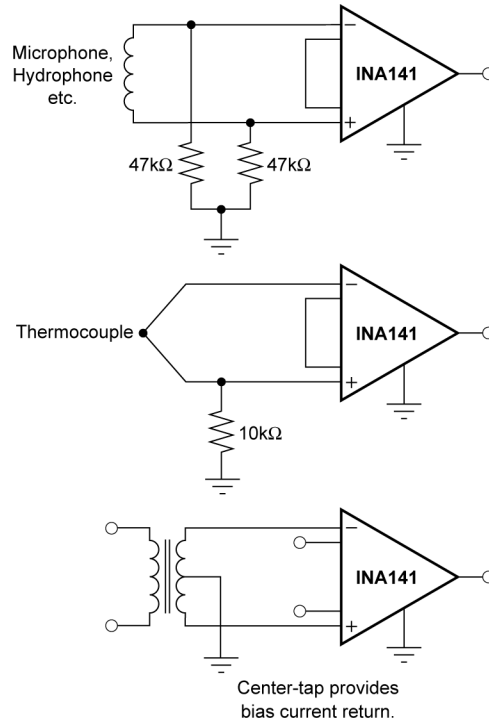


Figure 7-3. Providing an Input Common-Mode Current Path.

7.1.6 Input Common-Mode Range

The linear input voltage range of the input circuitry of the INA141 is from approximately 1.4 V less than the positive supply voltage to 1.7 V greater than the negative supply. As a differential input voltage causes the output voltage to increase, however, the linear input range is limited by the output voltage swing of amplifiers A₁ and A₂. Therefore, the linear common-mode input range is related to the output voltage of the complete amplifier. This behavior also depends on supply voltage (see the *Input Common-Mode Range vs Output Voltage* plots, [Figure 6-5](#) and [Figure 6-6](#)).

Input overload can produce an output voltage that appears normal. For example, if an input overload condition drives both input amplifiers to the positive output swing limit, the difference voltage measured by the output amplifier is near zero. The output of the INA141 is near 0 V even though both inputs are overloaded.

7.1.7 Low-Voltage Operation

The INA141 operates on power supplies as low as ± 2.25 V. Performance remains excellent with power supplies ranging from ± 2.25 V to ± 18 V. Most parameters vary only slightly through this supply voltage range—see Typical Performance Curves. Operation at a very low supply voltage requires careful attention to make sure that the input voltages remain within the linear range. Voltage swing requirements of internal nodes limit the input common-mode range with low power-supply voltage. The *Input Common-Mode Range vs Output Voltage* typical characteristics plots, [Figure 6-5](#) and [Figure 6-6](#), show the range of linear operation for ± 15 -V, ± 5 -V, and ± 2.5 -V supplies.

7.1.8 Input Protection

The inputs of the INA141 are individually protected for voltages up to ± 40 V. For example, a condition of -40 V on one input and $+40$ V on the other input does not cause damage. Internal circuitry on each input provides low series impedance under normal signal conditions. To provide equivalent protection, series input resistors contributes excessive noise. If the input is overloaded, the protection circuitry limits the input current to a safe value of approximately 1.50 mA to 5 mA. The inputs are protected even if the power supplies are disconnected or turned off.

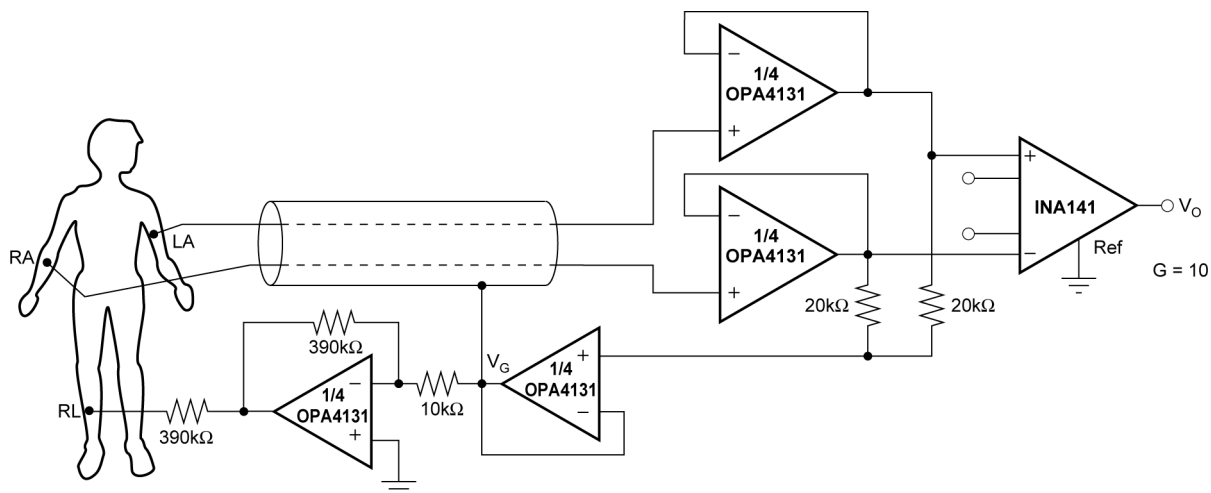


Figure 7-4. ECG Amplifier With Right-Leg Drive

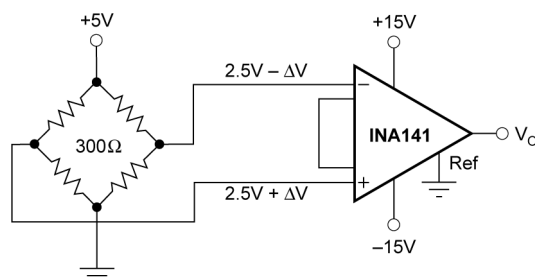


Figure 7-5. Bridge Amplifier

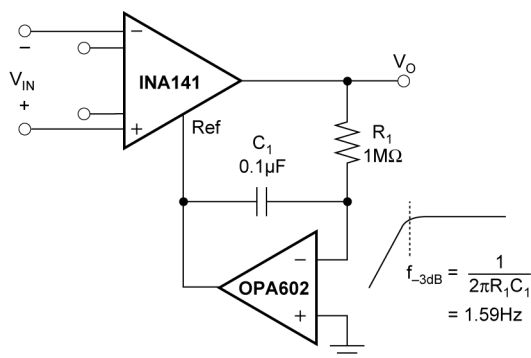
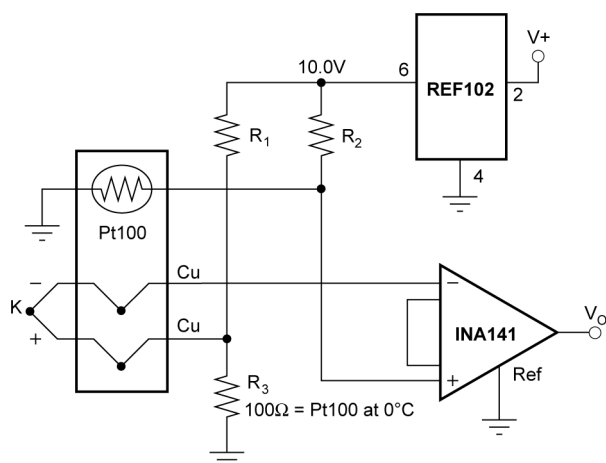


Figure 7-6. AC-Coupled Instrumentation Amplifier



ISA TYPE	MATERIAL	SEEBECK COEFFICIENT ($\mu\text{V}/^\circ\text{C}$)	R_1, R_2
E	+ Chromel – Constantan	58.5	66.5k Ω
J	+ Iron – Constantan	50.2	76.8k Ω
K	+ Chromel – Alumel	39.4	97.6k Ω
T	+ Copper – Constantan	38.0	102k Ω

Figure 7-7. Thermocouple Amplifier With RTD Cold-Junction Compensation

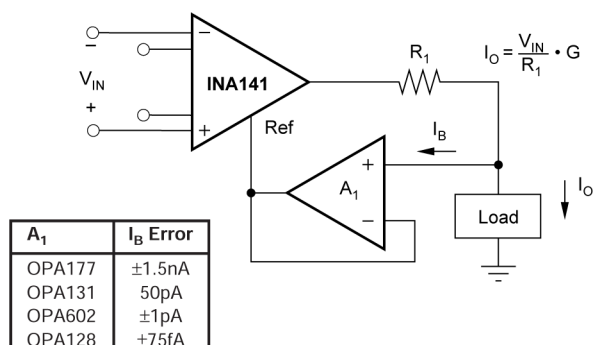


Figure 7-8. Differential Voltage-to-Current Converter

8 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

8.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.2 Support Resources

TI E2E™ [support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

8.3 Trademarks

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8.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.5 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

9 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
INA141U	Active	Production	SOIC (D) 8	75 TUBE	Yes	Call TI Nipdau	Level-3-260C-168 HR	-	INA 141U
INA141U.B	Active	Production	SOIC (D) 8	75 TUBE	Yes	Call TI	Level-3-260C-168 HR	-40 to 85	INA 141U
INA141U/2K5	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	Call TI Nipdau	Level-3-260C-168 HR	-	INA 141U
INA141U/2K5.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	Call TI	Level-3-260C-168 HR	-40 to 85	INA 141U
INA141UA	Active	Production	SOIC (D) 8	75 TUBE	Yes	Call TI Nipdau	Level-3-260C-168 HR	-40 to 85	INA 141U A
INA141UA.B	Active	Production	SOIC (D) 8	75 TUBE	Yes	Call TI	Level-3-260C-168 HR	-40 to 85	INA 141U A
INA141UA/2K5	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	Call TI Nipdau	Level-3-260C-168 HR	-40 to 85	INA 141U A
INA141UA/2K5.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	Call TI	Level-3-260C-168 HR	-40 to 85	INA 141U A

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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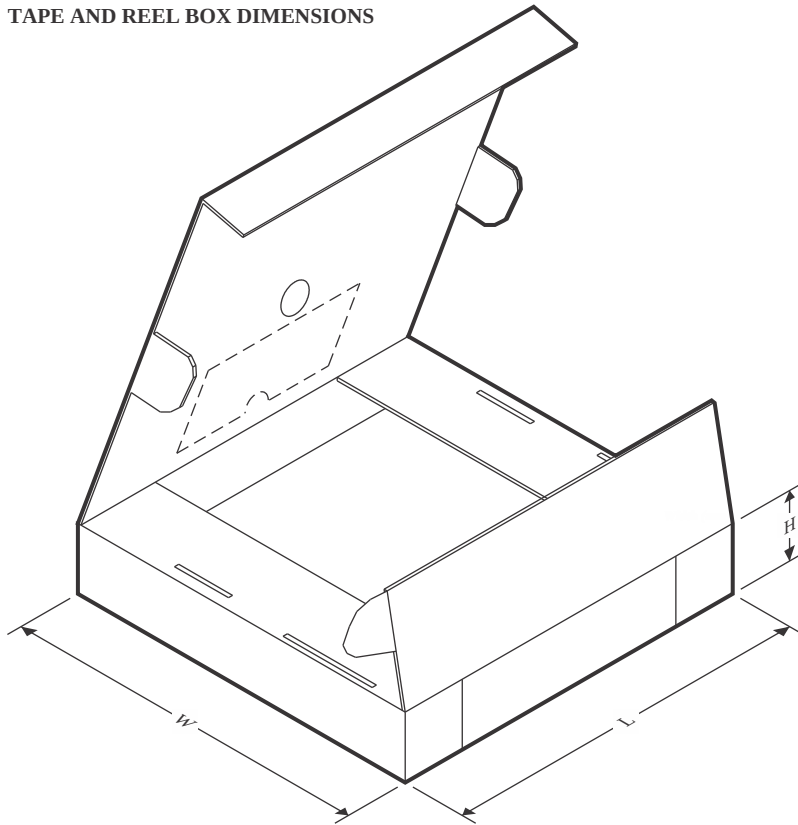
TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
INA141U/2K5	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
INA141U/2K5	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
INA141UA/2K5	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

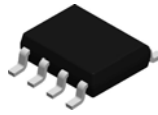
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
INA141U/2K5	SOIC	D	8	2500	367.0	367.0	35.0
INA141U/2K5	SOIC	D	8	2500	353.0	353.0	32.0
INA141UA/2K5	SOIC	D	8	2500	356.0	356.0	35.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
INA141U	D	SOIC	8	75	506.6	8	3940	4.32
INA141U.B	D	SOIC	8	75	506.6	8	3940	4.32
INA141UA	D	SOIC	8	75	506.6	8	3940	4.32
INA141UA.B	D	SOIC	8	75	506.6	8	3940	4.32

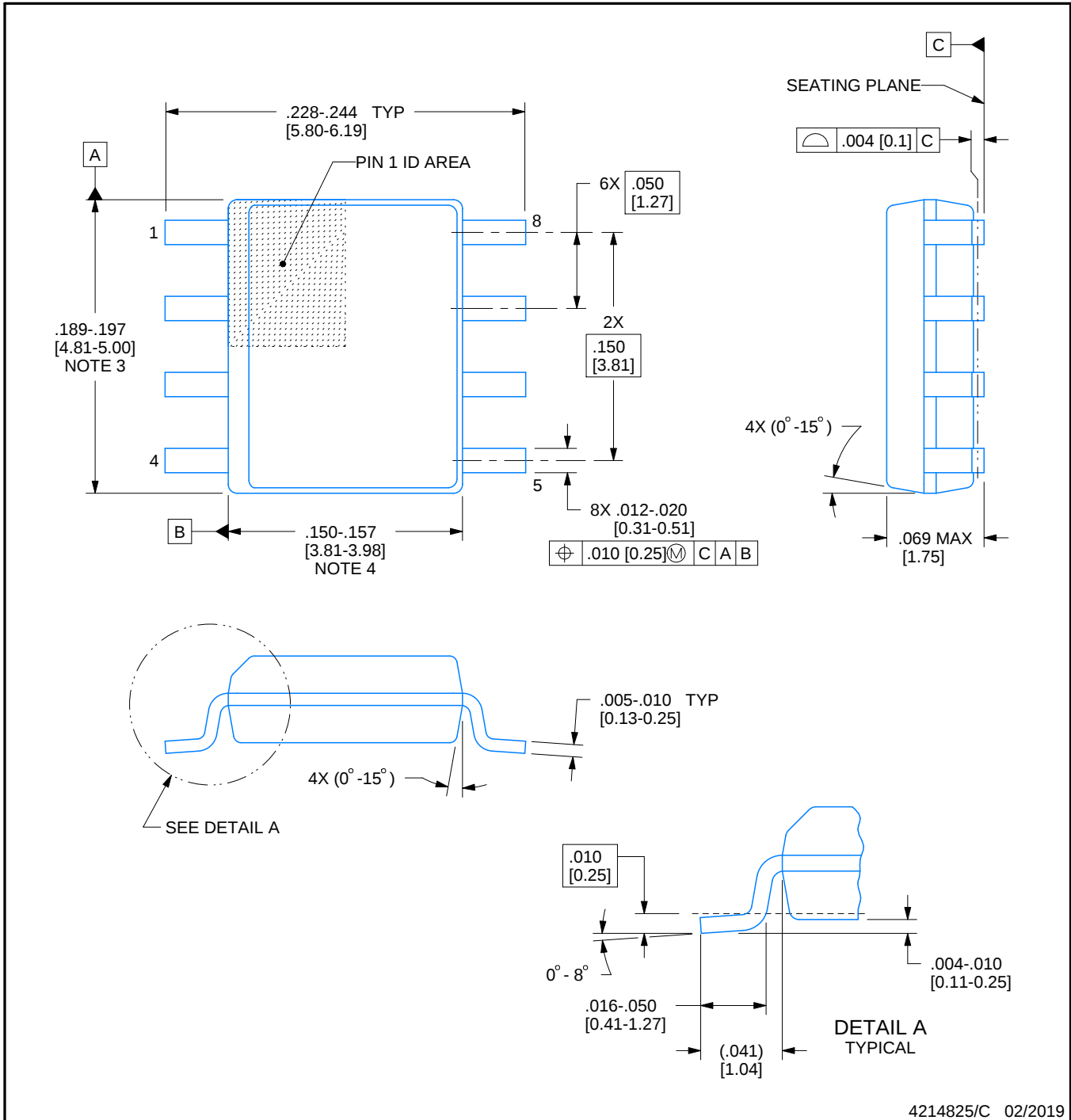


D0008A

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

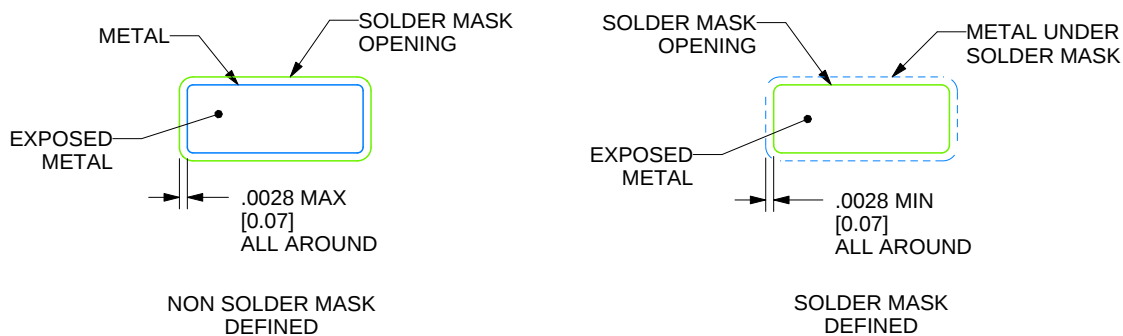
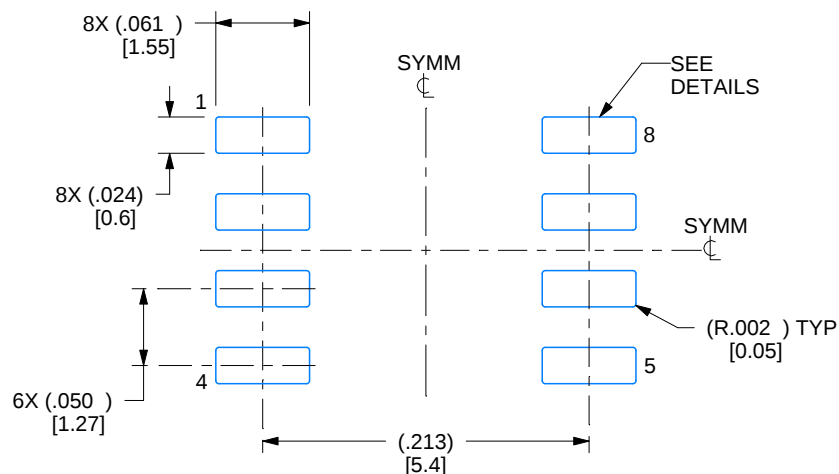
1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

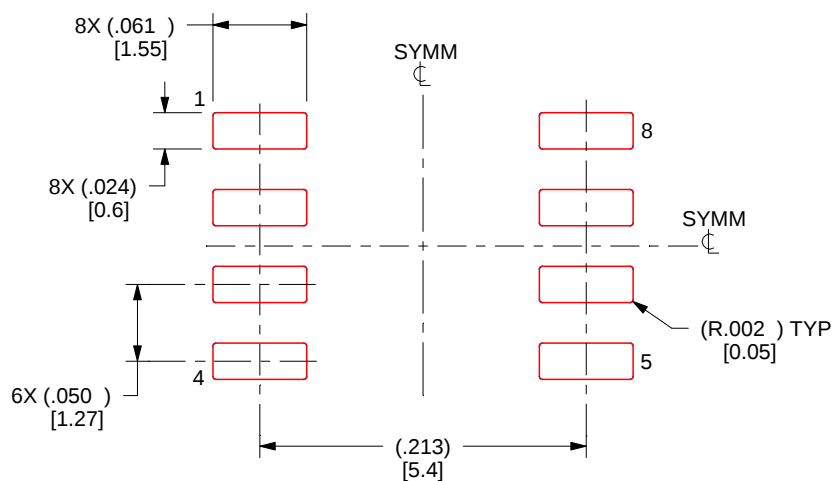
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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